## **Field Effect Transistor**

Silicon N Channel MOS Type ( $\pi$ -MOS II.5) High Speed, High Current DC-DC Converter, Relay Drive and Motor Drive Applications

#### **Features**

- Low Drain-Source ON Resistance
- $R_{DS(ON)} = 1.1\Omega$  (Typ.)
- High Forward Transfer Admittance
  - $|Y_{fs}| = 4.0S$  (Typ.)
- Low Leakage Current
  - $I_{DSS} = 300 \mu A \text{ (Max.)} @ V_{DS} = 720 V$
- Enhancement-Mode
  - $V_{th} = 1.5 \sim 3.5 V @ V_{DS} = 10 V$ ,  $I_D = 1 mA$

### Absolute Maximum Ratings (Ta = 25°C)

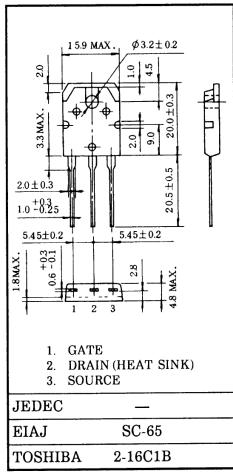
CHARACTERISTIC		SYMBOL	RATING	UNIT
Drain-Source Voltage		V <sub>DSS</sub>	900	V
Drain-Gate Voltage ( $R_{GS} = 20k\Omega$ )		V <sub>DGR</sub>	900	V
Gate-Source Voltage		V <sub>GSS</sub>	±30	V
Drain Current	DC	I <sub>D</sub>	9	А
	Pulse	I <sub>DP</sub>	27	
Drain Power Dissipation (Tc = 25°C)		P <sub>D</sub>	150	W
Channel Temperature		T <sub>ch</sub>	150	°C
Storage Temperature Range		T <sub>stg</sub>	-55 ~ 150	°C

#### **Thermal Characteristics**

CHARACTERISTIC	SYMBOL	MAX.	UNIT
Thermal Resistance, Channel to Case	R <sub>th(ch-c)</sub>	0.833	°C/W
Thermal Resistance, Channel to Ambient	R <sub>th(ch-a)</sub>	50	°C/W

This transistor is an electrostatic sensitive device. Please handle with care.

## Industrial Applications Unit in mm



Weight: 4.6g

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# Electrical Characteristics (Ta = 25°C)

CHAR	ACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Gate Leakage C	Current	I <sub>GSS</sub>	$V_{GS} = \pm 25V, V_{DS} = 0V$	-	_	±100	nA
Drain Cut-off C	urrent	I <sub>DSS</sub>	$V_{DS} = 720V, V_{GS} = 0V$	-	-	300	μA
Drain-Source B	Breakdown Voltage	V <sub>(BR) DSS</sub>	$I_D = 10$ mA, $V_{GS} = 0$ V	900	-	-	V
Gate Threshold	Voltage	V <sub>th</sub>	$V_{DS} = 10V$ , $I_D = 1mA$	1.5	-	3.5	V
Drain-Source C	N Resistance	R <sub>DS (ON)</sub>	I <sub>D</sub> = 4A, V <sub>GS</sub> = 10V	-	1.1	1.4	Ω
Forward Transf	er Admittance	Y <sub>fs</sub> I	$V_{DS} = 20V$ , $I_D = 4A$	2.0	4.0	-	S
Input Capacitance Reverse Transfer Capacitance Output Capacitance		C <sub>iss</sub>	$V_{DS} = 25V, V_{GS} = 0V,$ f = 1MHz	-	1300	1800	pF
		C <sub>rss</sub>		-	100	150	
		C <sub>oss</sub>		-	180	260	
	Rise Time	t <sub>r</sub>		-	25	50	
Switching	Turn-on Time	t <sub>on</sub>	V <sub>GS 0V</sub> T I <sub>D=4A</sub> V <sub>OUT</sub>	_	40	80	
Time	Fall Time	t <sub>f</sub>	$R_{L}=100\Omega$	-	20	40	ns
	Turn-off Time	t <sub>off</sub>	4 7	_	100	200	
			$V_{\text{IN}}: t_{\text{r}}, t_{\text{f}} < 5 \text{ns}, V_{\text{DD}} = 400 \text{V}$ $\text{Duty} \leq 1\%, t_{\text{W}} = 10 \mu \text{s}$				
Total Gate Charge (Gate-Source Plus Gate-Drain)		Qg	V <sub>DD</sub> = 400V, V <sub>GS</sub> = 10V, I <sub>D</sub> = 9A	_	120	240	nC
Gate-Source Charge		Q <sub>gs</sub>		-	70	-	
Gate-Drain ("M	liller") Charge	Q <sub>gd</sub>		-	50	-	

# Source-Drain Diode Ratings and Characteristics (Ta = 25°C)

CHARACTERISTICS	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Continuous Drain Reverse Current	I <sub>DR</sub>	-	-	-	9	Α
Pulse Drain Reverse Current	I <sub>DRP</sub>	_	-	-	27	Α
Diode Forward Voltage	V <sub>DSF</sub>	$I_{DR} = 9A$ , $V_{GS} = 0V$	-	-	-2.0	V

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**Notes** 

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6/6